

TRIAC series

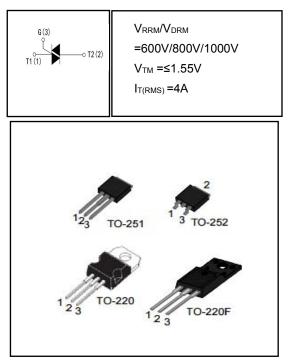
1 Description

BTB04 series triacs with low holding and latchingcurrent are especially recommended for use onmiddle and small resistance type power load.

TO-220F provides insulation voltage rated at 2000V RMS from all three terminals to external heatsink. TO-220F series comply with UL standards (File ref: E252906).

2 Features

- High current output up to 4A
- Low Peak on-state voltage drop
- High voltage
- High reliability
- 3 Applications
- jet pumps of dishwashers
- fans of air-conditioner
- power charger
- AC Motor control



4 Electrical Characteristics

4.1 Absolute Maximum Ratings (Tc=25°C, unless otherwise noted)

DADAMETED					
PARAMETER			SYMBOL	VALUE	UNIT
Repetitive peak off-state voltage (Tj=25°C)			V _{DRM}	600/800/1000	V
Repetitive peak reverse voltage (Tj=25℃)			V _{RRM}	600/800/1000	V
Non repetitive surge peak Off-state voltage			V _{DSM}	+ 100	V
Non repetitive peak reverse voltage			V _{RSM}	+ 100	V
RMS on-state current		20/TO-251/ ſc=110℃)	I _{T(RMS)}	4	A
		20F ∣05℃)			
	tp=8.3ms			42	۸
Non repetitive surge peak on-state current		p=10ms	I _{TSM}	40	A
I ² t value for fusing (tp=10ms)			l²t	8	А
Repetitive rate of rise of on-state current (ITM=20A IG=50mA dIG/dt 50mA/ms)			dıt/dt	50	A/us
Peak gate current			I _{GM}	2	А
Peak gate power			P _{GM}	5	W
Average gate power dissipation			P _{G(AV)}	1	W
Operating junction temperature range			TJ	- 40 ~ 125	°C
Storage junction temperature range			Tstg	- 40 ~ 150	°C

4.2 Thermal Characteristics

PARAMETER	SYMBOL		UNIT		
FARAMETER	STWDOL	TO-220	TO-220F	TO-252/251	
Thermal Resistance, Junction to Case-sink	R _{thJC}	2.8	4.0	3.7	°C/W



SYMBOL	PARAMETER	Test Conditions		Min	Тур	Max	Unit	
			I - II -III	-	7.0	10		
I _{GT}	Triggering gate current	V _D =12V R _L =33Ω	IV	-	-	-	mA	
V _{GT}	Triggering gate voltage	1	ALL	-	0.77	1.3	V	
V _{GD}	Non-triggering gate voltage	V _D =V _{DRM} T _j =125°CR _L =3.3KΩ		0.2	-	-	V	
			I -III	-	-	20		
١L	Latching Current	I _G =1.2I _{GT}	II	-	-	35	mA	
Ін	Holding Current	I⊤=100mA		-	-	20	mA	
d∨/dt	Critical Rate of Rise of Off-state Voltage	V _D =2/3V _{DRM} Gate Open T _j =125℃		20	-	-	V/us	
V _{TM}	Peak Forward On-State Voltage	I _{TM} =10A tp=380us		-	1.31	1.55	V	
I _{DRM}	Maximum forward or reverse leakage current		Tj=25 ℃	-	-	10	uA	
I _{RRM}	Maximum reverse leakage current	VD=VDRM VR=VRRM	Tj=125 ℃	-	-	1	mA	

4.3 Electrical Characteristics (Tc=25°C, unless otherwise noted)

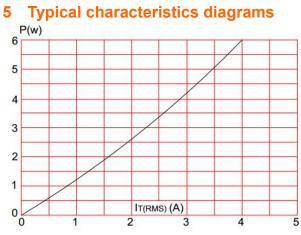


FIG.1: Maximum power dissipation versus RMS on-state current

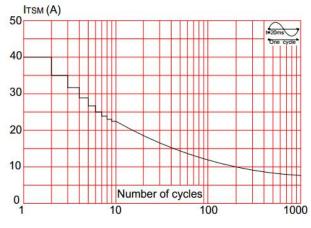
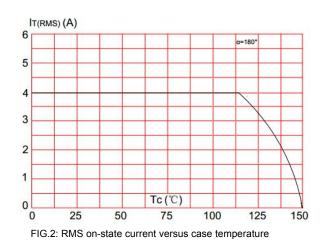
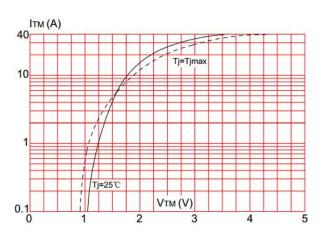
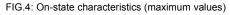


FIG.3: Surge peak on-state current versus number of cycles









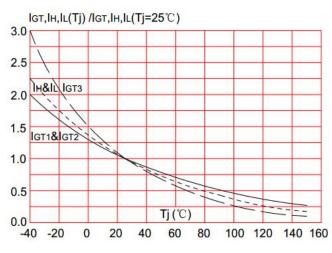
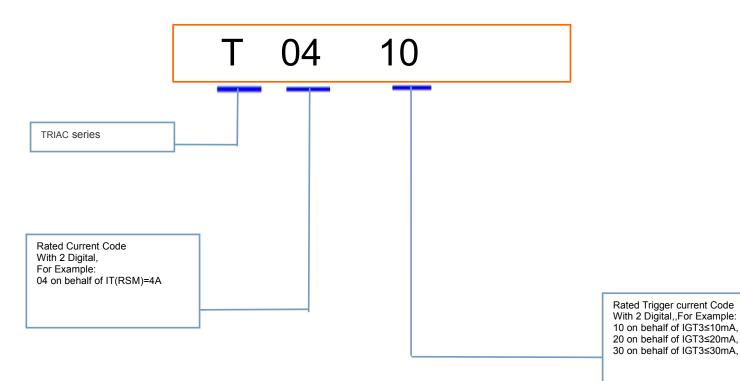


FIG.5: Relative variations of gate trigger current, holding current

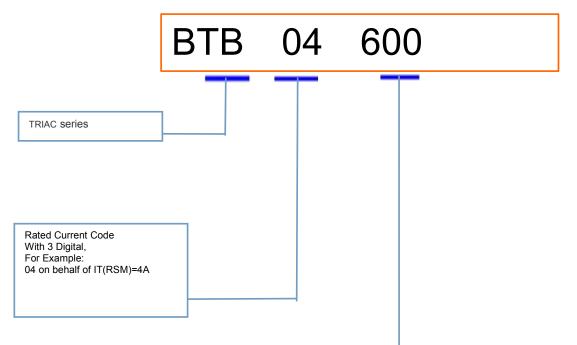
and latching current versus junction temperature

6 Product Names Rules





Bidirectional thyristor 4A series



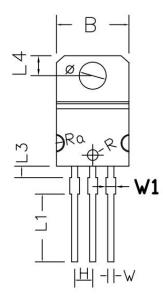
Rated Voltage Code With 3-4 Digital,For Example: 600on behalf of 600V, 800on behalf of 800V, 1000on behalf of 1000V,

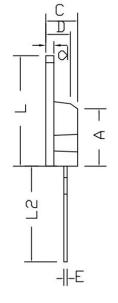
7 Product Specifications and Packaging Models

Product Model	Package Type	Mark Name	RoHS	Package	Quantity
BTB04	TO-220	BTB04	Pb-free	Tube	1000//box
BTB04	TO-252	T0410	Pb-free	Braid	3000//disc
BTB04	TO-220F	BTB04X	Pb-free	Tube	1000//box

8 Dimensions

TO-220M PACKAGE OUTLINE DIMENSIONS





Cumb a 1	Dimensions In	n Millimeters	Dimensions	In Inches
Symbol	min.	max.	min.	max.
	MIN	MAX	MIN	MAX
А	8.03	8.05	0.316	0.317
В	10.13	10.23	0.399	0.403
С	4.42	4.52	0.174	0.178
D	3.42	3.52	0.135	0.139
Е	0.44	0.46	0.017	0.018
L	15.25	15.45	0.601	0.609
Н	2.52	2.56	0.099	0.101
W	0.85	0.87	0.033	0.034
Φ	3.78	3.82	0.149	0.151
R	0.74	0.76	0.029	0.030
Ra	9.44	9.48	0.372	0.374
d	1.28	1.32	0.050	0.052
L1	9.4	9.6	0.370	0.378
L2	13. 22	13.62	0. 521	0.537
L3	1.52	1.72	0.060	0.068
L4	2.7	2.9	0.106	0.114
W1	1.32	1.42	0.052	0.056



0

В

0

Ή

0

W1

Bidirectional thyristor 4A series

TO-220 F PACKAGE OUTLINE DIMENSIONS

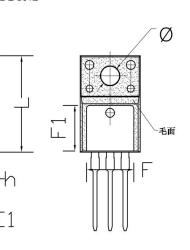
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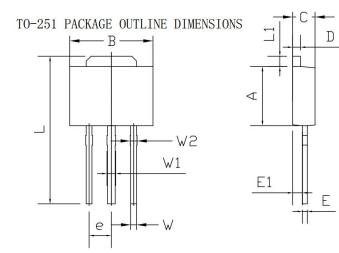
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D



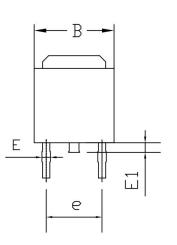
C	DimensionsIn	Millimeters	Dimension	sIn Inches
Symbol	min.	max.	min.	max.
A	8.80	9.30	0.346	0.366
В	10.00	10.50	0.394	0.413
С	4.30	4.90	0.169	0.193
D	2.30	2.70	0.091	0.106
L	15.55	16.15	0.612	0.636
h	0.40	0.60	0.016	0.024
L1	3.15	3.55	0.124	0.140
L2	12.65	13.35	0.498	0.526
W	0.70	0.90	0.028	0.035
W1	1.15	1.55	0.045	0.061
H	2.54	TYP	0.100 TYP	
E	0.48	0.53	0.019	0.021
φ	2.90	3.40	0.114	0.134
E1	2.40	2.90	0.094	0.114
F	7.75	8.25	0.305	0.325
F1	7.35	7.85	0.289	0.309

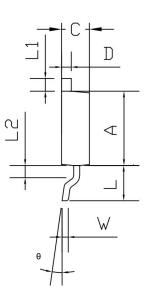


Symbol [Variable]	Dimensions I	n Millimeters	Dimensions	In Inches
Symbol	min.	max.	min.	max.
A	6.00	6.20	0.236	0.244
В	2.25	2.35	0.089	0.093
С	2.45	2.65	0.097	0.104
D	0.75	0.85	0.030	0.033
Е	8.48	8.52	0.3341	0.3357
E1	5.10	5.46	0.201	0.215
е	2.29	2.31	0.0902	0.0910
L	15.00	15. 40	0.5910	0.6068
L1	1.00	1.10	0.0394	0.0433
W	0.55	0.65	0.0217	0.0256
W1	0.85	0.95	0.0335	0.0374
W2	0.65	0.75	0.0256	0.0296



TO-252 PACKAGE OUTLINE DIMENSIONS





Comb - 1	Dimensions	In Millimeters	Dimensions	In Inches
Symbol	min.	max.	min.	max.
A	6.00	6.20	0.236	0.244
В	6.49	6.69	0.256	0.263
С	2.20	2.40	0.087	0.094
D	0.75	0.85	0.030	0.033
Е	0.65	0.75	0.0256	0.0296
E1	0.70	0.90	0.028	0.035
е	4.58	4.62	0.1805	0.1820
L	2.85	2.95	0.112	0.116
L1	1.00	1.10	0.0394	0.0433
L2	0.70	0.90	0.0276	0.0355
W	0.48	0.52	0.019	0.020
θ	0	8	0	8

9 Attentions

- Jiangsu Donghai Semiconductor Technology Co., Ltd. reserves the right to change the specification without prior notice! The customer should obtain the latest version of the information before making the order and verify that the information is complete and up to date.
- It is the responsibility of the purchaser for any failure or failure of any semiconductor product under certain conditions. It is the responsibility of the purchaser to comply with safety standards and to take safety measures in the system design and machine manufacturing of WXDH products in order to avoid potential risk of failure. Injury or property damage.
- Product promotion is endless, our company will be dedicated to provide customers with better products.

10 Appendix

Revision history:

Date	REV.	Description	Page
2017.08.14	1.0	Original	